

## Features

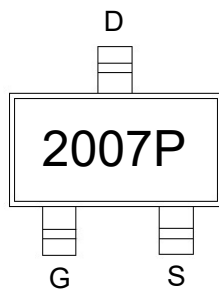
- Trench Power LV MOSFET technology
- High Density Cell Design for Low  $R_{DS(ON)}$
- High Speed switching

## Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
|----------|------------------|-----------|
| -20V     | 30mΩ@-4.5V       | -7A       |
|          | 40mΩ@-2.5V       |           |

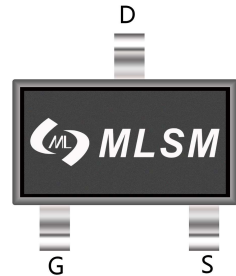
## Application

- Battery protection
- Load switch
- Power management

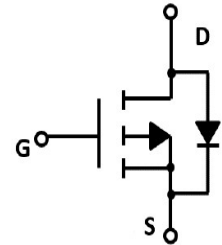


2007P: Device code

Marking and pin assignment



SOT-23-3L top view



Schematic diagram



Pb-Free



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

## Common Ratings (TC=25°C Unless Otherwise Noted)

|           |                                  |                        |    |
|-----------|----------------------------------|------------------------|----|
| $V_{DS}$  | Drain-Source Breakdown Voltage   | -20                    | V  |
| $V_{GS}$  | Gate-Source Voltage              | ±10                    | V  |
| $T_J$     | Maximum Junction Temperature     | 150                    | °C |
| $T_{STG}$ | Storage Temperature Range        | -55 to 150             | °C |
| $I_S$     | Diode Continuous Forward Current | $T_c=25^\circ\text{C}$ | -7 |
|           |                                  |                        | A  |

## Mounted on Large Heat Sink

|                 |                                        |                        |     |      |
|-----------------|----------------------------------------|------------------------|-----|------|
| $I_{DM}$        | Pulse Drain Current Tested             | $T_c=25^\circ\text{C}$ | -25 | A    |
| $I_D$           | Continuous Drain Current               | $T_c=25^\circ\text{C}$ | -7  | A    |
| $P_D$           | Maximum Power Dissipation              | $T_c=25^\circ\text{C}$ | 1.2 | W    |
| $R_{\theta JA}$ | Thermal Resistance Junction-to-Ambient |                        | 105 | °C/W |

## Ordering Information (Example)

| Type      | Package   | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|-----------|-----------|---------|----------------------|-------------------------|----------------------------|---------------|
| MLSK2007P | SOT-23-3L | 2007P   | 3,000                | 45,000                  | 180,000                    | 7"reel        |

| Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)             |                                  |                                                                                         |      |      |      |      |
|--------------------------------------------------------------------------------------|----------------------------------|-----------------------------------------------------------------------------------------|------|------|------|------|
| Symbol                                                                               | Parameter                        | Condition                                                                               | Min  | Typ  | Max  | Unit |
| Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)  |                                  |                                                                                         |      |      |      |      |
| B <sub>V(BR)DSS</sub>                                                                | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA                                             | -20  | –    | –    | V    |
| I <sub>DSS</sub>                                                                     | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =-18V, V <sub>GS</sub> =0V                                              | --   | –    | -1   | μA   |
| I <sub>GSS</sub>                                                                     | Gate-Body Leakage Current        | V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V                                              | --   | –    | ±100 | nA   |
| V <sub>GS(th)</sub>                                                                  | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA                               | -0.4 | -0.7 | -1.0 | V    |
| R <sub>DS(on)</sub>                                                                  | Drain-Source On-State Resistance | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A                                             | --   | 21   | 30   | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2A                                             | --   | 29   | 40   | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1A                                             | --   | 40   | 75   | mΩ   |
| Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated) |                                  |                                                                                         |      |      |      |      |
| C <sub>ISS</sub>                                                                     | Input Capacitance                | V <sub>DS</sub> =-9V, V <sub>GS</sub> =0V, f=1MHz                                       | –    | 1015 | –    | pF   |
| C <sub>OSS</sub>                                                                     | Output Capacitance               |                                                                                         | –    | 138  | –    | pF   |
| C <sub>RSS</sub>                                                                     | Reverse Transfer Capacitance     |                                                                                         | –    | 105  | –    | pF   |
| Switching Characteristics                                                            |                                  |                                                                                         |      |      |      |      |
| Q <sub>g</sub>                                                                       | Total Gate Charge                | V <sub>DS</sub> =-9V, I <sub>D</sub> =-5.6A, V <sub>GS</sub> =-4.5V                     | –    | 11.3 | –    | nC   |
| Q <sub>gs</sub>                                                                      | Gate Source Charge               |                                                                                         | –    | 2.3  | –    | nC   |
| Q <sub>gd</sub>                                                                      | Gate Drain Charge                |                                                                                         | –    | 2.4  | –    | nC   |
| t <sub>d(on)</sub>                                                                   | Turn-on Delay Time               | V <sub>DD</sub> =-9V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =2.5Ω | --   | 8.5  | –    | nS   |
| t <sub>r</sub>                                                                       | Turn-on Rise Time                |                                                                                         | –    | 35.5 | –    | nS   |
| t <sub>d(off)</sub>                                                                  | Turn-Off Delay Time              |                                                                                         | –    | 78   | –    | nS   |
| t <sub>f</sub>                                                                       | Turn-Off Fall Time               |                                                                                         | –    | 58   | –    | nS   |
| Source- Drain Diode Characteristics                                                  |                                  |                                                                                         |      |      |      |      |
| V <sub>SD</sub>                                                                      | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =-7A                                               | --   | –    | -1.2 | V    |

## Typical Operating Characteristics

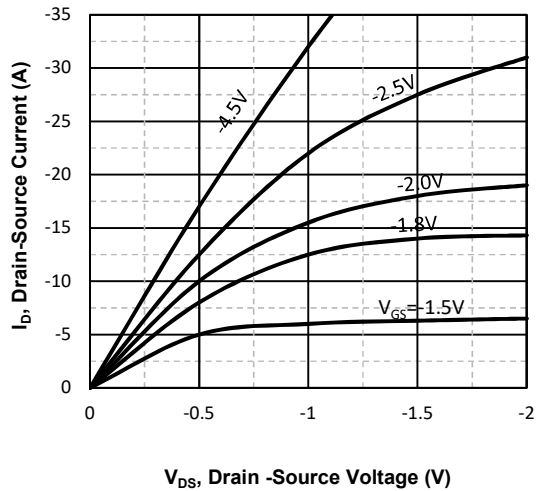


Fig1. Typical Output Characteristics

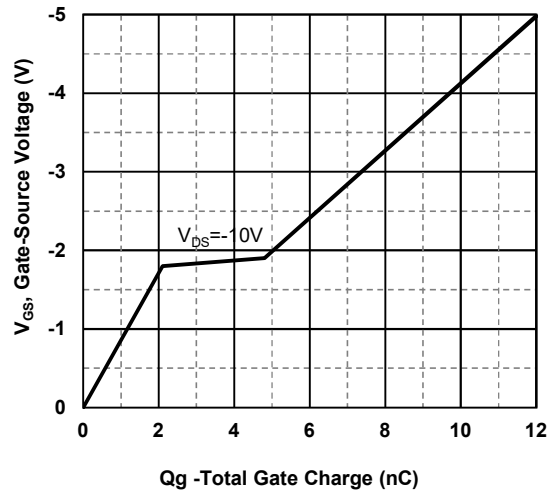


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

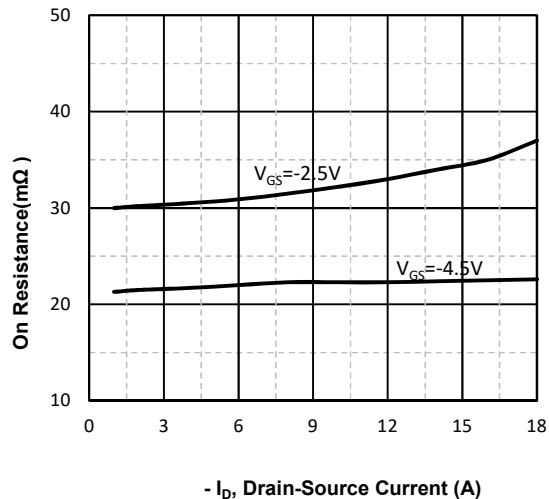


Fig3. Drain-Source on Resistance

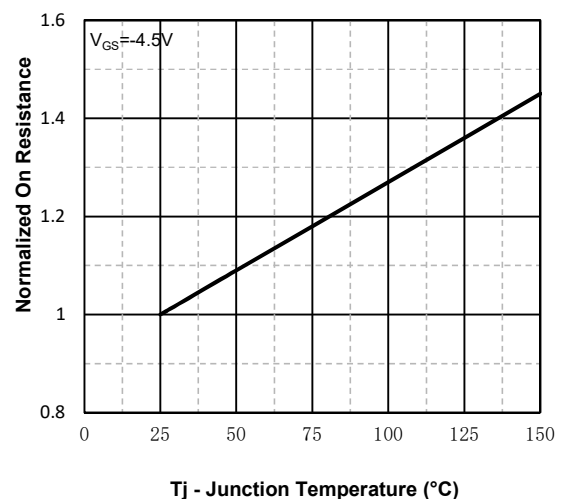


Fig4. Normalized On-Resistance Vs. Temperature

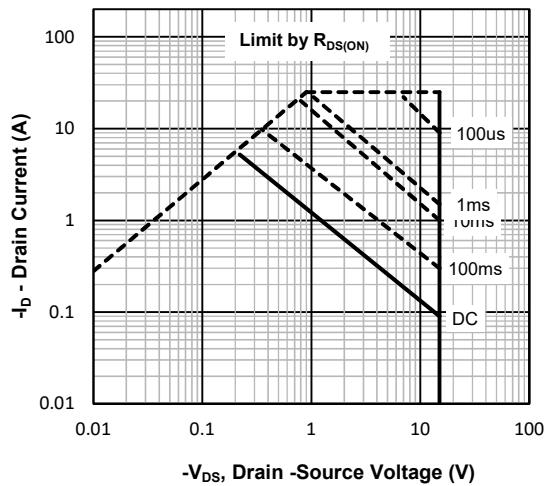


Fig5. Maximum Safe Operating Area

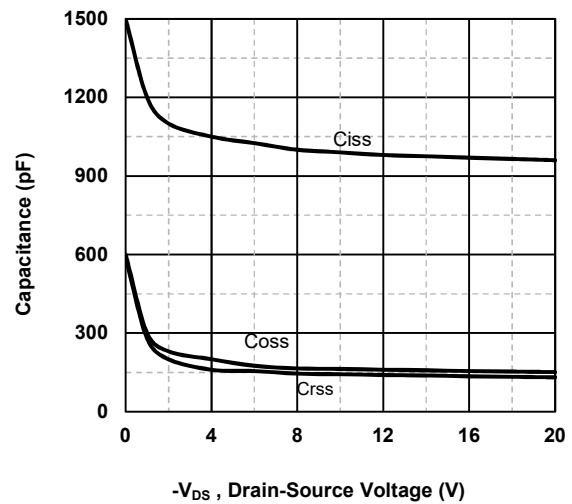
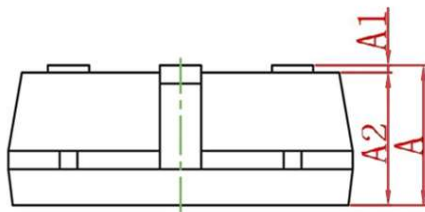
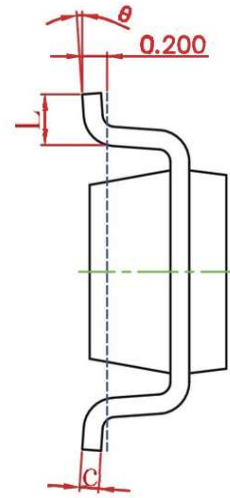
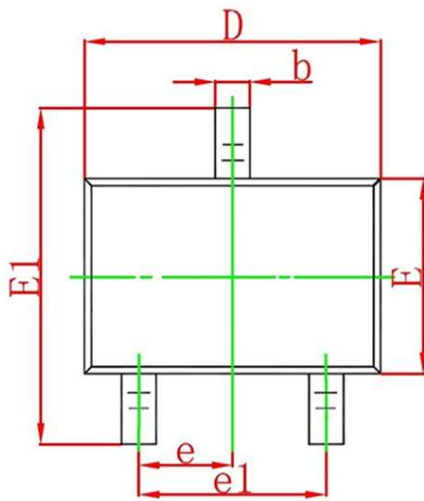


Fig6 Typical Capacitance Vs. Drain-Source Voltage

**SOT-23-3L Package information**



| Symbol   | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|----------|-------------------------------|-------|----------------------|-------|
|          | Min                           | Max   | Min                  | Max   |
| A        | 1.050                         | 1.250 | 0.042                | 0.050 |
| A1       | 0.000                         | 0.100 | 0.000                | 0.004 |
| A2       | 1.050                         | 1.150 | 0.042                | 0.046 |
| b        | 0.300                         | 0.500 | 0.012                | 0.020 |
| c        | 0.100                         | 0.200 | 0.004                | 0.008 |
| D        | 2.820                         | 3.020 | 0.112                | 0.120 |
| E        | 1.500                         | 1.700 | 0.060                | 0.068 |
| E1       | 2.650                         | 2.950 | 0.106                | 0.118 |
| e        | 0.950TYP                      |       | 0.037TYP             |       |
| e1       | 1.800                         | 2.000 | 0.071                | 0.079 |
| L        | 0.300                         | 0.600 | 0.012                | 0.024 |
| $\theta$ | 0°                            | 8°    | 0°                   | 8°    |